PNP Epitaxial Silicon Transistor

BD136 Series

BD136 / BD138 / BD140

Applications

- Complement to BD135, BD137 and BD139 Respectively
- These are Pb-Free Devices

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^{\circ}C$ unless otherwise noted)

Rating		Symbol	Max	Unit
Collector-Base Voltage	BD136 BD138 BD140	V _{CBO}	-45 -60 -80	V
Collector-Emitter Voltage	BD136 BD138 BD140	V _{CEO}	-45 -60 -80	V
Emitter-Base Voltage		V _{EBO}	-5	V
Collector Current (DC)		I _C	-1.5	А
Collector Current (Pulse)		I _{CP}	-3.0	А
Base Current		I _B	-0.5	А

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Rating	Symbol	Мах	Unit
Collector Dissipation	P _C	12.5	W
Collector Dissipation ($T_A = 25^{\circ}C$)	P _C	1.25	W
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{STG}	-55~150	°C

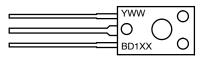


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MARKING DIAGRAM





ORDERING INFORMATION

Device	Package	Shipping	
BD13610STU		60 Units/ Tube	
BD13610S		500 Units/ Bulk Box	
BD13616STU		60 Units/ Tube	
BD13616S	TO-126	500 Units/ Bulk Box	
BD13810STU	(Pb-Free)	60 Units/ Tube	
BD13816STU		60 Units/ Tube	
BD14010STU		60 Units/ Tube	
BD14016STU		60 Units/ Tube	
BD14016S		500 Units/ Bulk Box	

BD136 Series

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage (Note 1) BD136 BD138 BD140	I _C = -30 mA, I _B = 0	-45 -60 -80			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -30$ V, $I_E = 0$			-0.1	μA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5 V, I_{C} = 0$			-10	μΑ
h _{FE1}	DC Current Gain (Note 1)	V_{CE} = -2 V, I_C = -5 mA	25			
h _{FE2}		V _{CE} = -2 V, I _C = -150 mA BD13610/BD13810/BD14010 BD13616/BD13816/BD14016	63 100		160 250	
h _{FE3}	1	V_{CE} = -2 V, I_C = -500 mA	25			
V _{CE} (sat)	Collector-Emitter Saturation Voltage (Note 1)	I _C = 500 mA, I _B = 50 mA			-0.5	V
V _{BE} (on)	Base-Emitter ON Voltage (Note 1)	$V_{CE} = -2 V, I_{C} = -0.5 A$			-1	V

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: PW = 350 μs, duty Cycle = 2% Pulsed

BD136 Series

TYPICAL PERFORMANCE CHARACTERISTICS

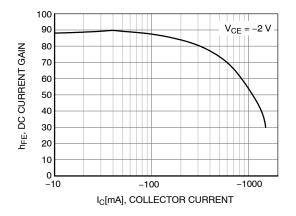


Figure 1. DC Current Gain

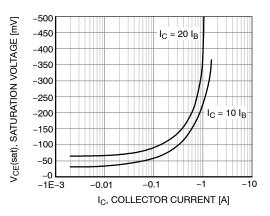


Figure 2. Collector-Emitter Saturation Volatage

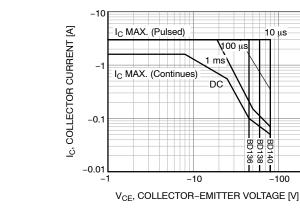


Figure 4. Safe Operating Area

-100

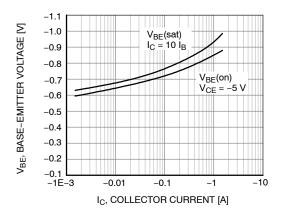


Figure 3. Base-Emitter Voltage

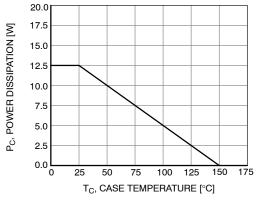
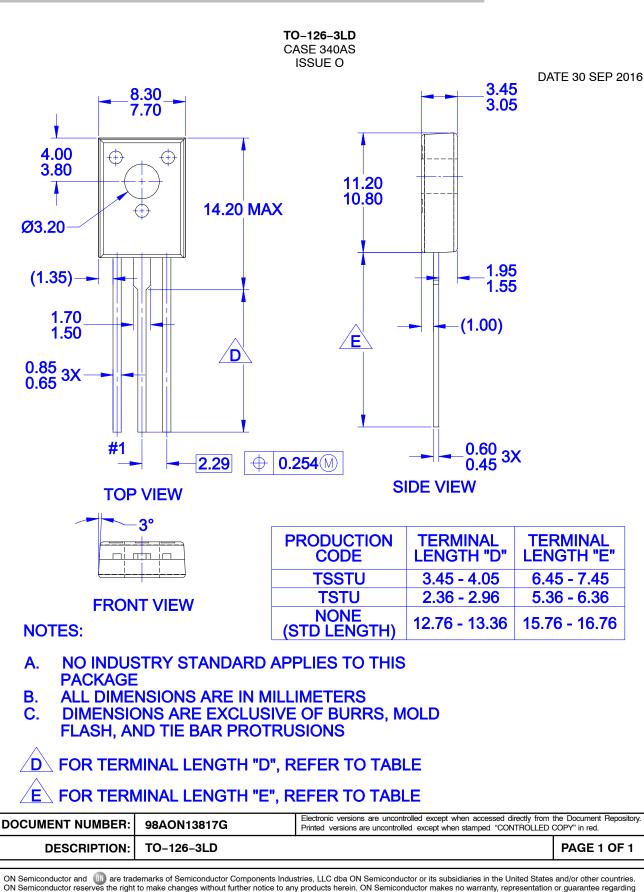


Figure 5. Power Derating





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